



Microscopic Investigation of Flux Trapping Sites in Bulk Nb

Martina Martinello, Zu-Hawn Sung, Sam Posen, Jaeyel Lee, Anna Grassellino, Alex Romanenko

International Conference on RF Superconductivity

2 July 2019

Outline

- Introduction on pinning
- Insights from flux expulsion studies in Nb cavities
- Microscopy studies of Nb "as-received" materials with different flux expulsion properties
- Microscopy studies of cavity cut-outs with different flux expulsion properties
- Conclusions



What pinning means and why it occurs

Pinning \Rightarrow minimization of the system energy

- Vortex lowers locally the condensation energy of the SC (within length $\sim 2\xi$)
- Defects also lower locally the condensation energy of the SC, and, depending on the type of defect, the change may be more or less dramatic
- <u>When vortices are pinned in defects the overall</u> <u>loss in condensation energy of the SC is</u> <u>minimized</u>
- The most efficient minimization of energy happen when pinning centers have dimension comparable to $\sim 2\xi$ (for niobium in clean limit $\xi \cong 38 nm$ at 2K and $\xi \cong 150 - 300 nm$ close to Tc)



Possible pinning sites in Nb









- Normal-conducting and dielectric inclusions:
 3-D defects that introduce large κ variation (ex: nano-hydrides in the near-surface area)
- **<u>Grain boundaries</u>**: 2-D defects in the crystal structure, they define the interface between 2 grains.
 - Low-angle GBs: the misorientation between the two grains is <15 degrees</p>
- <u>Dislocations</u>: areas were the atoms are out of position in the crystal structure.
 - <u>Tangles</u>: after plastic deformation very small grain forms (cells) that are surrounded by tangles of dislocations
- <u>Local disorder</u>: 1-D defects (ex: impurities, vacancies)



Possible pinning sites in Nb



Normal-conducting and dielectric inclusions: 3-D defects that introduce large κ variation (ex: nano-hydrides in the near-surface area)



oms are out of

ation between the





Tangles: after plastic deformation very small grain forms (cells) that are surrounded by tangles of dislocations

are

Local disorder: 1-D defects (ex: impurities, vacancies)



in Nb SRF cavities?

Outline

- Introduction on pinning
- Insights from flux expulsion studies in Nb cavities
- Microscopy studies of Nb "as-received" materials with different flux expulsion properties
- Microscopy studies of cavity cut-outs with different flux expulsion properties
- Conclusions



Facts about flux expulsion

- <u>Flux expulsion in Nb cavities is promoted in presence of large thermal-gradient</u> (fast cool-down) during SC transition [A. Romanenko et al., Appl. Phys. Lett. **105**, 234103 (2014); A. Romanenko et al., J. Appl. Phys. **115**, 184903 (2014)]
- <u>Flux expulsion is a **bulk property**</u> \rightarrow does not depend on surface treatment [S. Posen et al., J. Appl. Phys. **119**, 213903 (2016)]
- Not all materials show good flux expulsion, even with large thermal gradient during the SC transition \rightarrow high T treatments allow to improve materials flux expulsion properties [S. Posen et al., J. Appl. Phys. 119, 213903 (2016)]



Considerations on cavities with different level of flux expulsion

Flux expulsion studies in Nb cavities:

• All data shown after baking at 800C for 3h





Considerations on cavities with different level of flux expulsion

Flux expulsion studies in Nb cavities:

• All data shown after baking at 800C for 3h







Considerations on cavities with different level of flux expulsion

Flux expulsion studies in Nb cavities:

• All data shown after baking at 800C for 3h

Large grain cavity do not reach full
flux expulsion
➢ GBs cannot be the only flux trapping sites in Nb cavities



Cavities made out with materials coming from different Nb vendors show different flux expulsion properties

🛟 Fermilab

Outline

- Introduction on pinning
- Insights from flux expulsion studies in Nb cavities
- Microscopy studies of Nb "as-received" materials with different flux expulsion properties
- Microscopy studies of cavity cut-outs with different flux expulsion properties
- Conclusions



At Nb vendors



From Hiroaki Umezawa, CTO Tokyo Denkai Co., Ltd. – TTC 2017 MSU





At Nb vendors

From Hiroaki Umezawa, CTO Tokyo Denkai Co., Ltd. – TTC 2017 MSU Cold work \rightarrow introduces dislocations and dislocations tangles

‡Fermilab





At Nb vendors

From Hiroaki Umezawa, CTO Tokyo Denkai Co., Ltd. – TTC 2017 MSU





At Nb vendors

From Hiroaki Umezawa, CTO Tokyo Denkai Co., Ltd. – TTC 2017 MSU





At Nb vendors

🛟 Fermilab

 Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition ATI -good flux expulsion-

Ningxia -bad flux expulsion-



- Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition
- Material with bad flux expulsion properties shows small grains, many with high level of local misorientation

ATI -good flux expulsion-

Ningxia -bad flux expulsion-



 Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition

with

Material

bad

flux

ATI -good flux expulsion-

Ningxia -bad flux expulsion-



Which types of defects are present in grains with high level of local misorientation?



 Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition

Material

with bad

flux

ATI -good flux expulsion-

Ningxia -bad flux expulsion-

Local misorientation map

컃 Fermilab



Which types of defects are present in grains with high level of local misorientation?

STEM studies of defective region in "as-received" material

Local misorientation map

- High resolution EBSD in asreceived material
- Area with high level of local misorientation identified
- TEM lamella prepared to study the area in details
 - Transmission EBSD
 - ➢ BF-STEM
 - ► HR-TEM





ROI for TEM sample cutout

















🛟 Fermilab



‡ Fermilab









Linear def

Dislo

200 nm

High density of dislocations and tangles in the proximity of low angle GBs
Dislocations tangles possibly strong pinning centers close to Tc

μm

‡ Fermilab

BF-SILM overview

rnational Conference on RF Superconductivity, Dresden, 2019





 Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition ATI -good flux expulsion-

Ningxia -bad flux expulsion-





So...why relation between flux expulsion and dimensions of grains?





🚰 Fermilab

 Material that shows good flux expulsion properties (after annealing at 900C) has <u>larger grain</u> in the "as received" condition ATI -good flux expulsion-

Ningxia -bad flux expulsion-



Material expulsion	Sowhy relation between flux	1> 2>
small grai	expulsion and dimensions of	5 > 15 > 20 > 30 > 15
level of IC	grains?	
GBs	s block dislocations movement,	
ther	refore grains with high density of	
disle	ocations are found even after	
anne	ealing	
		Fermilab



Linear def

Dislo

200 nm

High density of dislocations and tangles in the proximity of low angle GBs
Dislocations tangles possibly strong pinning centers close to Tc

μm

‡ Fermilab

BF-SILM overview

rnational Conference on RF Superconductivity, Dresden, 2019



Tc

Dislo

200 nm

High density of dislocations and tangles in the proximity of low angle GBs
Dislocations tangles possibly strong pinning centers close to

Do we have dislocation tangles in Nb cavities?

ECCI studies in CAVITY CUT-OUTS Fermilab

Outline

- Introduction on pinning
- Insights from flux expulsion studies in Nb cavities
- Microscopy studies of Nb "as-received" materials with different flux expulsion properties
- Microscopy studies of cavity cut-outs with different flux expulsion properties
- Conclusions



Overview cavity fabrication, processing and test







Overview cavity fabrication, processing and test







Overview cavity fabrication, processing and test

At research institutes





Cavity cut-outs generated from a non perfectly expelling cavity

Ningxia cavity (RTDNX02):

- Very poor flux expulsion after 3h at 800C
- Little improvement after subsequent annealing at 900C for 3h
- Some improvement after subsequent annealing at 950C for 3h

Medium flux expulsion properties after annealing at 0.9 5 ∆T During Cooldown [K] 975C for 3h 0.09 P_{diss}=8.6W, Q₀=9.3e+09, E_{acc}=25.0MV/m, T=1.50K - P_{dies}=0.6W, Q₀=1.2e+11, E_{acc}=24.0MV/m, T=1.51K 0.08 Cold spots: 0.07 Hot spots: 0.06 regions that regions that 0.05 expelled flux trapped flux 0.04 efficiently even with fast 0.03 0.02 cooldown 0.01 19 25 30 36 12 18 Board # 0

For more info related to the T-map study see S. Posen talk, TTC 2018, Milan: https://agenda.infn.it/event/13791/contributions/21011/



EBSD analysis of hot- and cold- spot cross-sections

• EBSD of top-view and cross-section of cavity cut-outs



EBSD analysis of hot- and cold- spot cross-sections

- EBSD of top-view and cross-section of cavity cut-outs
- <u>Smaller grains</u> and higher density of <u>low-angle GBs</u> <u>in hot-spot</u>, more evident from top view than crosssection



EBSD analysis of hot- and cold- spot cross-sections

- EBSD of top-view and cross-section of cavity cut-outs
- <u>Smaller grains</u> and higher density of <u>low-angle GBs</u> <u>in hot-spot</u>, more evident from top view than crosssection
- Higher level of <u>local</u> <u>misorientation</u> in hot-spot, more evident from top view than cross-section



Electron Channeling Contrast Imaging (ECCI) for dislocations imaging

- ECCI is a scanning electron microscope (SEM) technique that makes use of the *electron channeling* mechanism.
- When electrons channel down through the crystal, local distortions in the crystal lattice yield a modulation in the backscatter electron (BE) signal.
 - Crystal defects such as dislocations can be imaged by ECCI
- The optimum channeling contrast in ECCI is obtained by orienting the crystal exactly into a channeling condition for a selected set of intense diffracting lattice planes
 - All images in the presentation were acquired along <200>channeling band



The presence of an edge dislocation convert an open channel to a closed one





Dislocations in the middle of large grains



Dislocations in the middle of large grains



Dislocations in the middle of large grains





Cold Spot

Larger density of dislocations in hot spot than in cold spot within large grains

 $0.3 N_{disl}/\mu m^2$



Martina Martinello | International Conference on RF Superconductivity, Dresden, 2019

 $1.8 N_{disl}/\mu m^2$

Dislocations in the middle of small grains



Dislocations in the middle of small grains



Dislocations at low-angle grain boundaries



Dislocations at highly strained region



Dislocations at highly strained region



Summary results from ECCI in Hot and Cold spot

- No clear presence of dislocations tangles in cavity cut-outs
- Density of dislocations overall larger in hot spot than in cold spot
- Small grains and areas with large local misorientation show larger density of dislocations and lattice defects
- Areas in which dislocations are closely spaced to each other are stronger pinning centers compared to isolated dislocations





Outline

- Introduction on pinning
- Insights from flux expulsion studies in Nb cavities
- Microscopy studies of Nb "as-received" materials with different flux expulsion properties
- Microscopy studies of cavity cut-outs with different flux expulsion properties
- Conclusions



Conclusions – as received material



- Grain boundaries are not expected to be strong pinning center close to Tc (d << coherence length close to Tc, $\xi \sim 200$ nm)
- GBs block dislocations movement, therefore grains with high density of dislocations are found even after annealing → smaller grains are usually found in bad flux expelling material
- Dislocations tangles are expected to be stronger pinning center than GBs, they can affect an area as large of many 100s of nanometers (d ~ ξ)
 - No clear presence of dislocations tangles in cavity cut-outs
- Presence of many regions with very high density of dislocations, affected area of ~ 200-300nm \rightarrow possibly strong pinning center close to Tc (d ~ ξ)

🛟 Fermilab

Conclusions – as received material



- Grain boundaries are not expected to be strong pinning center close to Tc (d << coherence length close to Tc, $\xi \sim 200$ nm)
- GBs block dislocations movement, therefore grains with high density of dislocations are found

Areas with closely spaced dislocations are, most likely, the most effective pinning center in Nb cavities close to Tc, and therefore responsible of flux trapping



cavity cut-outs

• Presence of many regions with very high density of dislocations, affected area of ~ 200-300nm \rightarrow possibly strong pinning center close to Tc (d ~ ξ)

🚰 Fermilab

ras rescan</mark>ternational Conference on RF Superconductivity, Dresden, 2019

Acknowledgments

A special thanks to:

- Dr. Zu-Hawn Sung, Dr. Sam Posen, Dr. Jaeyel Lee, Dr. Anna Grassellino, Dr. Alex Romanenko, Dr. Mattia Checchin and all the FNAL SRF R&D team for experimental and intellectual contributions
- Hank Han, Minming Wang, Prof. Martin Crimp, Prof. Carl Bohelert, Prof. Thomas Bieler (Michigan State University) for helping acquiring ECCI data and for useful discussion about ECCI and dislocations

Founding agencies: DOE-HEP and LCLS-II (DOE-BES)



Thank you for your attention!